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Schottky Barrier Rectifier 1.0 Amp, 20 and 40 Volt

DESCRIPTION

Single schottky rectifier assembled in Powermite 1 package which features a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly. The package also incorporates a unique locking tab which acts as an efficient heat path from the die to the mounting plane for external heat sinking with very low thermal resistance junction to case (bottom). This product is suitable for use in switching and regulating power supplies and also charge pump circuits.

Important: For the latest information, visit our website http://www.microsemi.com.

FEATURES

- Ultra low forward voltage drop.
- Efficient heat path with integral locking bottom metal tab.
- Supplied in 8mm tape and reel.
- RoHS compliant.

APPLICATIONS / BENEFITS

- High power surface mount package.
- Guard ring construction for transient protection.
- Compatible with Automatic Insertion Equipment.
- Full-metallic bottom eliminates flux entrapment.
- High surge capacity.
- Ideal for OR'ing diode.

MAXIMUM RATINGS @ 25 °C unless otherwise stated

Parameters/Test Conditions	Symbol	Value		Unit
Parameters/ rest conditions	Symbol	UPS5817	UPS5819	Unit
Peak Repetitive Reverse Voltage and also	V _{RRM}	20	40	V
Working Peak Reverse Voltage	V _{RWM}			
DC Blocking Voltage	V _R			
RMS Reverse Voltage	V _{R(RMS)}	14	28	V
Junction and Storage Temperature	$T_{\rm J}$ and $T_{\rm STG}$	-55 to	+150	°C
Thermal Resistance Junction-to-Case	R _{eJC}	15		ºC/W
Thermal Resistance Junction-to-Ambient ⁽¹⁾	R _{eja}	24	0	ºC/W
Average Rectified Output Current @ T _C = 135 °C	lo	1.	0	Α
Repetitive Peak Forward Current	I _{FRM}	2.0		Α
Surge Peak Forward Current		50)	Α
Voltage Rate of Change @ Rated V_R and $T_J = 25 \ ^{\circ}C$	dv/dt	10,000		V/µs
Solder Temperature @ 10 s	T _{SP}	260		°C

Notes: 1. Mounted on FR-4 PC board using 1 oz copper with recommended minimum foot print.





Powermite 1 (DO-216AA) Package

MSC – Lawrence

6 Lake Street, Lawrence, MA 01841 Tel: 1-800-446-1158 or (978) 620-2600 Fax: (978) 689-0803

MSC – Ireland

Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 Fax: +353 (0) 65 6822298

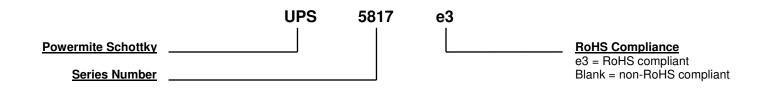
Website: www.microsemi.com



MECHANICAL and PACKAGING

- CASE: Molded epoxy package meets UL94V-0.
- TERMINALS: Copper with annealed matte-tin plating for RoHS compliance. Solderable per MIL-STD-750 method 2026. (Consult factory for tin-lead plating).
- MARKING: Body marked with "S17" or "S19".
- POLARITY: Cathode designated by Tab 1 (bottom).
- TAPE & REEL option: Packaging per EIA-481-B with 8 mm tape. Consult factory for quantities.
- WEIGHT: Approximately 0.016 grams.
- See Package Dimensions on last page.

PART NOMENCLATURE



ELECTRICAL CHARACTERISTICS

RATING (Conditions)		SYMBOL	VA UPS5817	LUE UPS5819	UNIT
Maximum Instantaneous Forward Voltage (2)	(I _F = 1.0 A, T _J = +25 ^o C)	V _F	0.45	0.55	Volts
Maximum Instantaneous Reverse Current (2)	$(V_R = 20 V, T_J = +25 \ ^{\circ}C)$	I _{RM}	1.0	1.0	mA
Typical Junction Capacitance	(V _R = 5V, f = 1 MHz)	CJ	105	60	pF

Notes: 2. Measured with a test pulse of 380 μ s to minimize self-heating effect.



GRAPHS

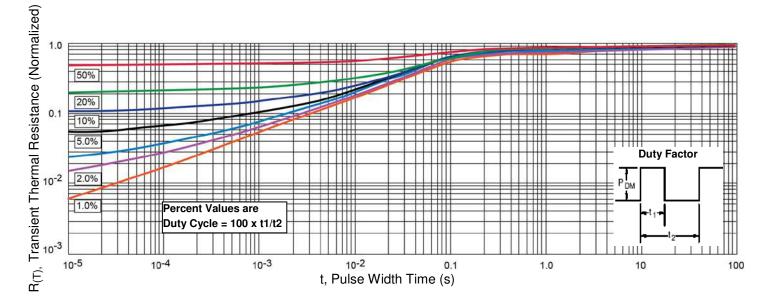


FIGURE 1 Thermal Impedance Junction to Case

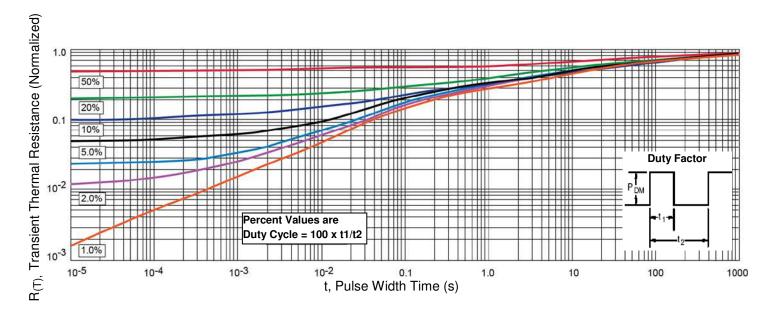
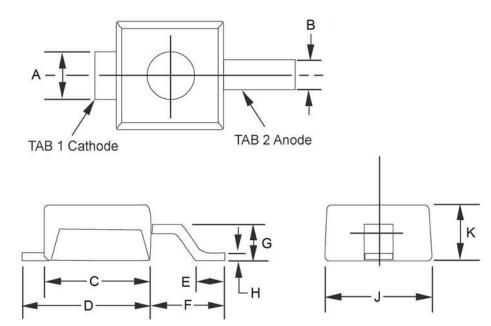


FIGURE 2 Thermal Impedance Junction to Ambient



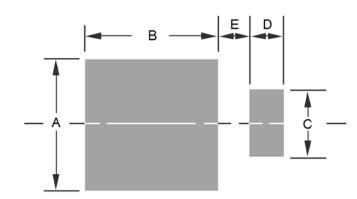
UPS5817(e3) and UPS5819(e3)

PACKAGE DIMENSIONS



	Dimensions			
Ltr	Inch		Millim	neters
	Min	Max	Min	Max
Α	0.029	0.039	0.73	0.99
В	0.016	0.026	0.40	0.66
С	0.070	0.080	1.77	2.03
D	0.087	0.097	2.21	2.46
E	0.020	0.030	0.50	0.76
F	0.051	0.061	1.29	1.54
G	0.021	0.031	0.53	0.78
Н	0.004	0.008	0.10	0.20
J	0.070	0.080	1.77	2.03
Κ	0.035	0.045	0.89	1.14

PAD LAYOUT



	Dimensions		
Ltr	Inch	Millimeters	
Α	0.100	2.54	
В	0.105	2.67	
С	0.050	1.27	
D	0.030	0.76	
E	0.025	0.64	

SCHEMATIC

